

5A, 20V - 200V Surface Mount Schottky Barrier Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for over-voltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

MECHANICAL DATA

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

KEY PARAMETERS						
PARAMETER	VALUE	UNIT				
I _{F(AV)}	5	А				
V _{RRM}	20 - 200	V				
I _{FSM}	120	А				
T _{J MAX}	150	°C				
Package	DO-214AB (SMC)					
Configuration	Single die					





DO-214AB (SMC)

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)												
PARAMETER	SYMBOL	SK	SK	SK	SK	SK	SK	SK	SK	SK	UNIT	
FARAMETER	UTINDUL	52C	53C	54C	55C	56C	59C	510C	515C	520C		
Marking code on the device		SK 52C	SK 53C	SK 54C	SK 55C	SK 56C	SK 59C	SK 510C	SK 515C	SK 520C		
Repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	90	100	150	200	V	
Reverse voltage, total rms value	V _{R(RMS)}	14	21	28	35	42	63	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	90	100	150	200	V	
Forward current	I _{F(AV)}					5					Α	
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}					120					A	
Critical rate of rise of off-state voltage	dV/dt	10,000				V/µs						
Junction temperature	T_{J}	- 55 to +150				°C						
Storage temperature	T _{STG}	T _{STG} - 55 to +150					°C					



THERMAL PERFORMANCE						
PARAMETER	SYMBOL	ТҮР	UNIT			
Junction-to-lead thermal resistance per diode	R _{θJL}	17	°C/W			
Junction-to-ambient thermal resistance per diode	R _{eJA}	50	°C/W			

PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
	SK52C					
	SK53C			-	0.55	V
	SK54C					
Forward voltage per diode ⁽¹⁾	SK55C SK56C	I _F = 5A, T _J = 25°C	V _F	-	0.75	V
r official voltage per cloue	SK59C	IF = 0, (, 1 J = 20 0	• F		0.05	V
	SK510C			-	0.85	V
	SK515C				0.95	V
	SK520C			-	0.95	V
	SK52C					
	SK53C					
	SK54C			-	0.5	mA
Reverse current @ rated V _R	SK55C					
per diode ⁽²⁾	SK56C	$T_J = 25^{\circ}C$	I _R			-
	SK59C					
	SK510C		-	0.3	mA	
	SK515C					
	SK520C					
	SK52C SK53C			-	20	mA
	SK53C SK54C					
	SK54C SK55C					
Reverse current @ rated V_R per diode ⁽²⁾	SK56C	T _J = 100°C		-	10	mA
per diode ⁽²⁾	SK50C	1j=100 C	I _R			
	SK510C					
	SK515C			-	-	mA
	SK520C					
	SK52C					
	SK53C			-	-	mA
Reverse current @ rated V _R	SK54C					
	SK55C	T= 125°C I _R				
	SK56C		Ь	-	-	mA
per diode ⁽²⁾	SK59C		-1X			
	SK510C				_	
	SK515C			-	5	mA
	SK520C					

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms



ORDERING INFORMATION							
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING		
	Н	R7		SMC	850 / 7" Plastic reel		
		R6	G	SMC	3,000 / 13" Paper reel		
SK5xxC (Note 1,2)		M6		SMC	3,000 / 13" Plastic reel		
(100le 1,2)		V7		Matrix SMC	850 / 7" Plastic reel		
		V6		Matrix SMC	3,000 / 13" Plastic reel		

Note :

1. "xx" defines voltage from 20V (SK52C) to 200V (SK520C)

2. Only V6 and V7 are all green compound (halogen free)

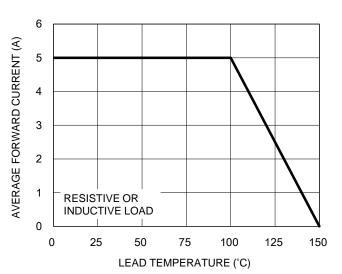
EXAMPLE					
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
SK52CHR7G	SK52C	Н	R7	G	AEC-Q101 qualified Green compound

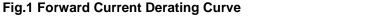


Fig.2 Typical Junction Capacitance

CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$





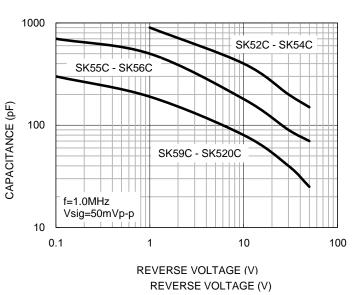
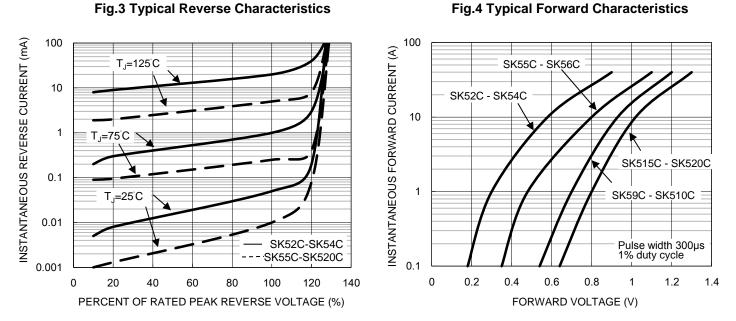


Fig.4 Typical Forward Characteristics

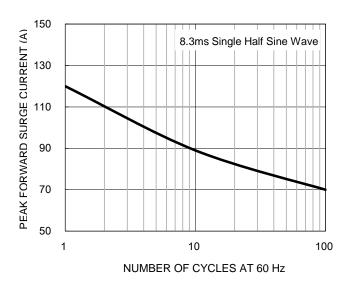




CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.5 Maximum Non-repetitive Forward Surge Current



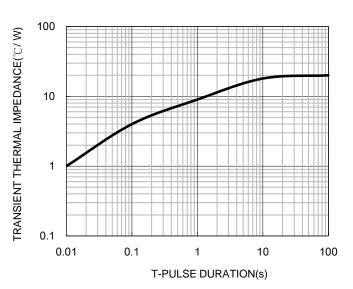
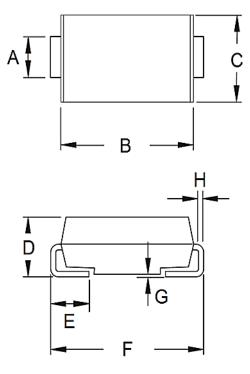


Fig.6 Typical Transient Thermal Characteristics



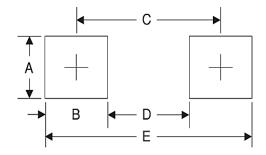
PACKAGE OUTLINE DIMENSIONS

DO-214AB (SMC)



DIM.	Unit	(mm)	Unit (inch)		
	. Min. Max.		Min.	Max.	
А	2.90	3.20	0.114	0.126	
В	6.60	7.11	0.260	0.280	
С	5.59	6.22	0.220	0.245	
D	2.00	2.62	0.079	0.103	
E	1.00	1.60	0.039	0.063	
F	7.75	8.13	0.305	0.320	
G	0.10	0.20	0.004	0.008	
Н	0.15	0.31	0.006	0.012	

SUGGESTED PAD LAYOUT

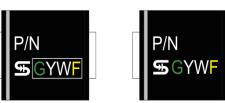


Symbol	Unit (mm)	Unit (inch)
А	3.30	0.130
В	2.50	0.098
С	6.80	0.268
D	4.40	0.173
E	9.40	0.370

MARKING DIAGRAM



SMC



- P/N =Marking Code
- G =Green Compound
- YW =Date Code
- F =Factory Code



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